NSN 5962-01-368-3810

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-368-3810

Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Am-7315/spy-1 e/i fscm 02769
Features Provided:
Programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Input Circuit Pattern:
20 input
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital fused pal
Voltage Rating And Type Per Characteristic:
4.5 volts positive power supply span and 5.5 volts positive power supply span
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Special Features:
Programmed per "bf6710168-2"
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883

standard (includes industry or association standards, individual manufactureer standards, etc.). And 67268-84129 standard (includes

Terminal Type And Quantity:

24 printed circuit

Purchase Description Identification:

industry or association standards, individual manufactureer standards, etc.).

5371-16-710-1682

Chalf Life:

NSN 5962-01-368-3810

Memory Microcircuit - Page 2 of 2



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Demilitarization:

Yes - demil/mli

Fiig:

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